



UTD405

Power MOSFET

P-CHANNEL ENHANCEMENT MODE

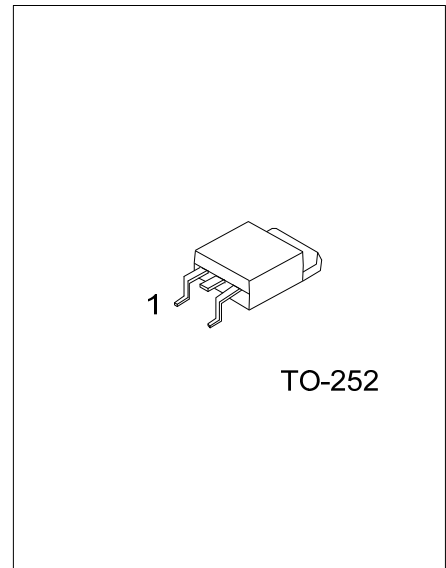
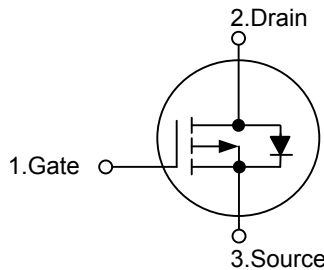
DESCRIPTION

The **UTD405** can provide excellent $R_{DS(ON)}$, low gate charge and low gate resistance by using advanced trench technology. This device is well suited for high current load applications with the excellent thermal resistance.

FEATURES

- * $R_{DS(ON)} = 32m\Omega @ V_{GS} = -10 V$
- * Low capacitance
- * Low gate charge
- * Fast switching capability
- * Avalanche energy specified

SYMBOL



*Pb-free plating product number: UTD405L

ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Normal	Lead Free Plating		1	2	3	
UTD405-TN3-R	UTD405L-TN3-R	TO-252	G	D	S	Tape Reel
UTD405-TN3-T	UTD405L-TN3-T	TO-252	G	D	S	Tube

<p>UTD405L-TN3-R</p> <p>(1)Packing Type</p> <p>(2)Package Type</p> <p>(3)Lead Plating</p>	<p>(1) R: Tape Reel, T: Tube</p> <p>(2) TN3: TO-252</p> <p>(3) L: Lead Free Plating, Blank: Pb/Sn</p>
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■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V_{DSS}	-30	V
Gate-Source Voltage	V_{GSS}	± 20	V
Continuous Drain Current	I_D	-18	A
Pulsed Drain Current	I_{DM}	-40	A
Avalanche Current	I_{AR}	-18	A
Repetitive Avalanche Energy(L=0.1mH)	E_{AR}	40	mJ
Power Dissipation	P_D	2.5	W
Junction Temperature	T_J	+150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55 ~ +150	$^{\circ}\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Junction-to-Ambient	θ_{JA}		40	50	$^{\circ}\text{C}/\text{W}$

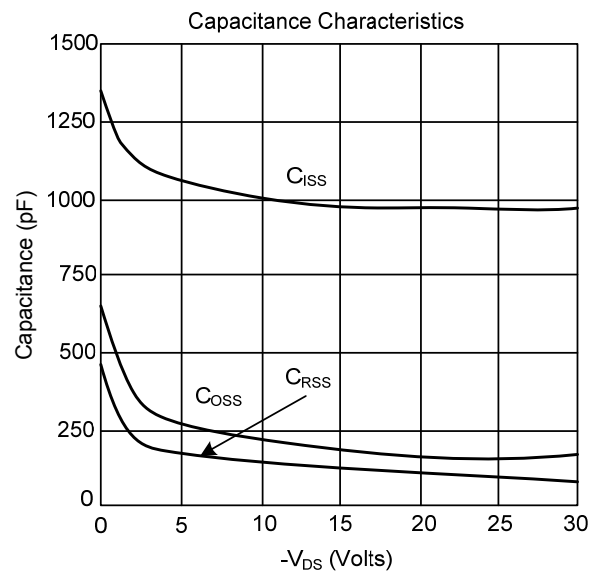
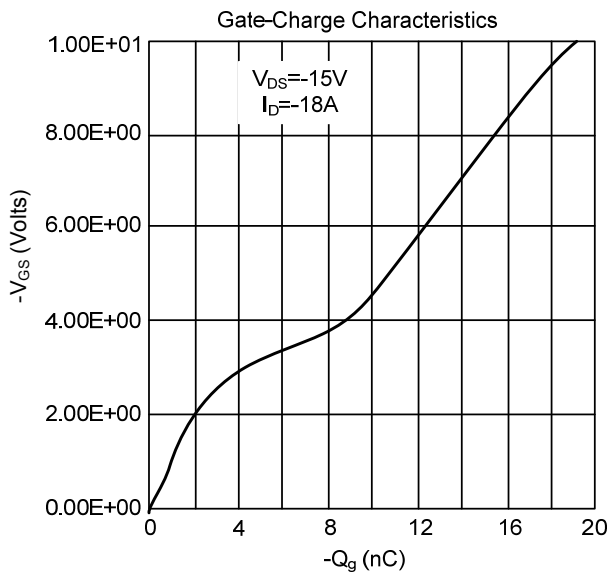
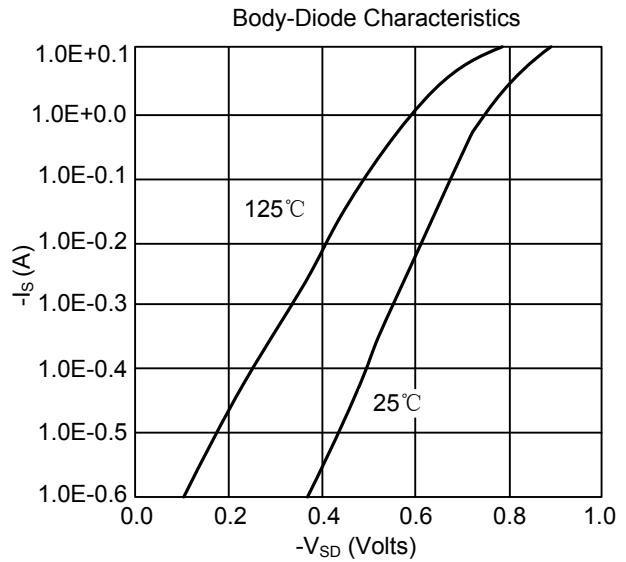
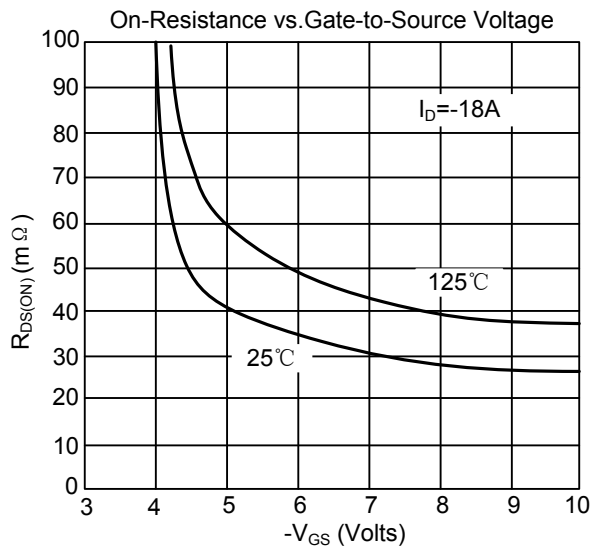
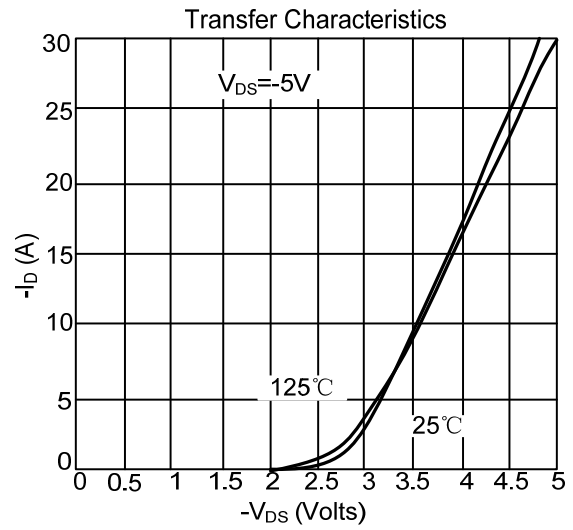
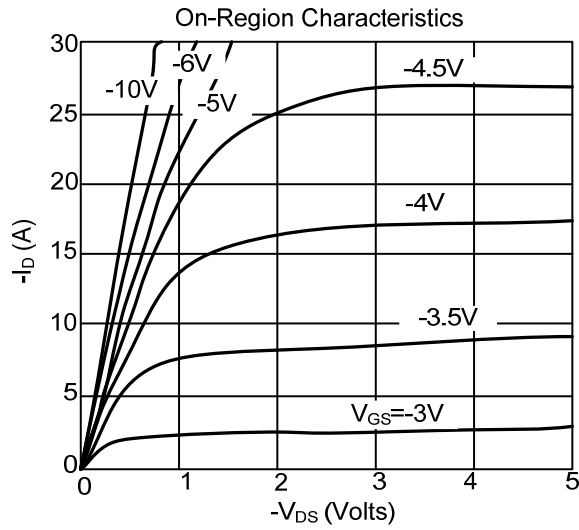
■ ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}\text{C}$, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0\text{ V}, I_D=-250\ \mu\text{A}$	-30			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=-24\text{ V}, V_{GS}=0\text{ V}$		-0.003	-1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{DS}=0\text{ V}, V_{GS}=\pm 20\text{V}$			± 100	nA
ON CHARACTERISTICS						
Gate-Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=-250\ \mu\text{A}$	-1.2	-2	-2.4	V
On state drain current	$I_{D(ON)}$	$V_{GS}=-10\text{V}, V_{DS}=-5\text{V}$	-40			A
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=-10\text{ V}, I_D=-18\text{A}$		24.5	32	m Ω
		$V_{GS}=-4.5\text{ V}, I_D=-10\text{A}$		41	60	m Ω
DYNAMIC PARAMETERS						
Input Capacitance	C_{ISS}	$V_{DS}=-15\text{ V}, V_{GS}=0\text{V}, f=1\text{MHz}$		920	1100	pF
Output Capacitance	C_{OSS}			190		pF
Reverse Transfer Capacitance	C_{RSS}			122		pF
SWITCHING PARAMETERS						
Total Gate Charge	Q_G	$V_{DS}=-15\text{V}, V_{GS}=-10\text{V}, I_D=-18\text{ A}$		18.7	23	nC
Gate-Source Charge	Q_{GS}			2.54		nC
Gate-Drain Charge	Q_{GD}			5.4		nC
Turn-ON Delay Time	$t_{D(ON)}$	$V_{GS}=-10\text{V}, V_{DS}=-15\text{V}, R_L=0.82\ \Omega, R_{GEN}=3\ \Omega$		9	13	ns
Turn-ON Rise Time	t_R			25	35	ns
Turn-OFF Delay Time	$t_{D(OFF)}$			20	30	ns
Turn-OFF Fall-Time	t_F			12	18	ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Drain-Source Diode Forward Voltage	V_{SD}	$I_S=-1\text{A}, V_{GS}=0\text{V}$		-0.76	-1	V
Maximum Continuous Drain-Source Diode Forward Current	I_S				-18	A
Body Diode Reverse Recovery Time	t_{RR}	$I_F=-18\text{A}, dI/dt=100\text{A}/\mu\text{s}$		21.4	26	ns
Body Diode Reverse Recovery Charge	Q_{RR}	$I_F=-18\text{A}, dI/dt=100\text{A}/\mu\text{s}$		13	16	nC

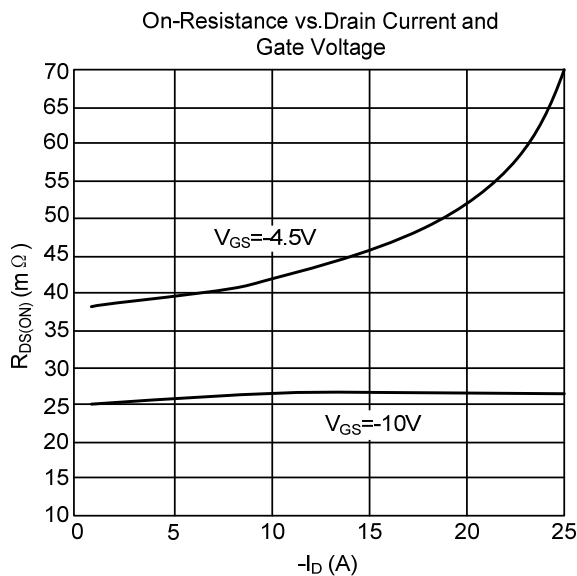
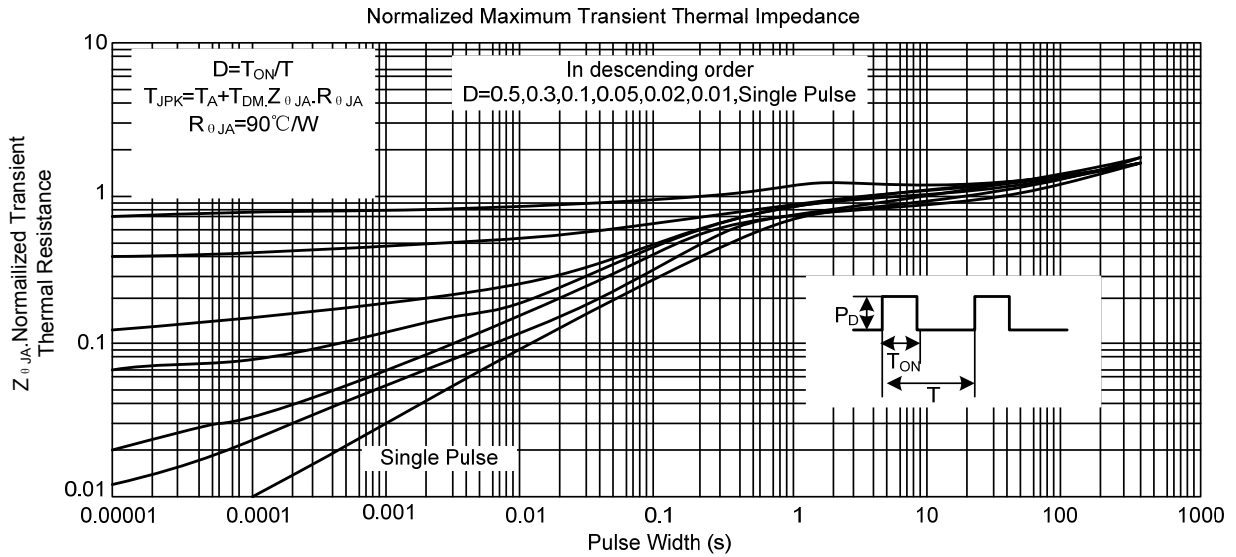
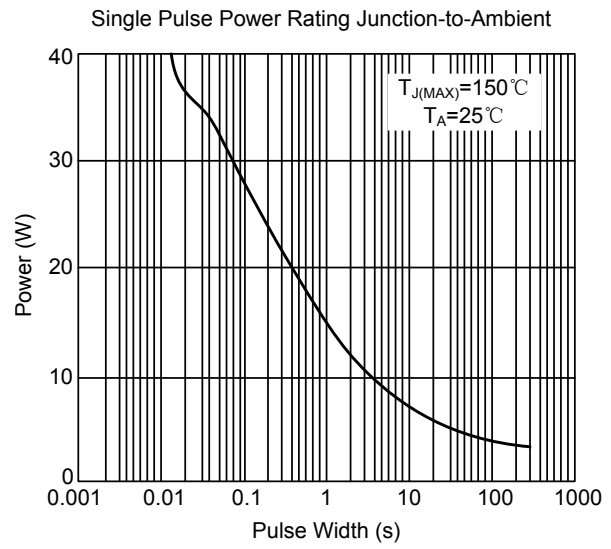
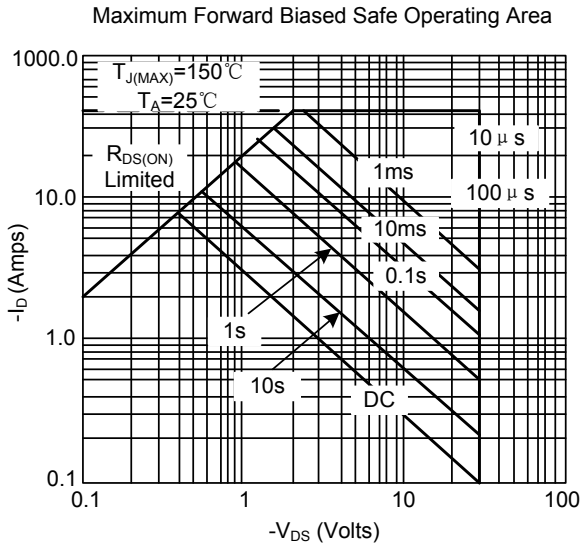
Notes: 1. Pulse width limited by $T_{J(MAX)}$

2. Pulse width $\leq 300\ \mu\text{s}$, duty cycle 0.5% max.

TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



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